

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LV5026M — LED Driver IC

Overview

LV5026M is a High Voltage LED drive controller which drives LED current up to 3A with external MOSFET. LV5026M is realized very simple LED circuits with a few external parts. It corresponds to various wide dimming controls including the TRIAC dimming control.

Functions

- High Voltage LED Controller
- Various Dimming Control
- -TRIAC & Analog Input & PWM Input
- Soft Start function
- Built-in TRIAC stabilized function
- Built-in circuit of detection of overvoltage of CS pin.
- Selectable Switching frequency [50 kHz or 70 kHz, open: 50 kHz]
- Short Protection Circuit
- Selectable reference Voltage
 - -Internal 0.605V & External Input Voltage
- Low noise switching system
 - 5 stages skip mode Frequency
 - Soft driving

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum Input voltage	V _{IN} max		-0.3 to 42	V
REF_OUT, REF_IN, RT, CS, PWM_D, ACS			-0.3 to 7	V
OUT1 pin	V _{OUT} _abs		-0.3 to 42	V
OUT2 pin	V _{OUT} 2_abs		-0.3 to 42	V
Allowable power dissipation	Pd max	With specified board*	1.0	W
Junction temperature	Tj		150	°C
Operating temperature	Topr		-30 to +125	°C
Storage temperature	Tstg		-40 to +150	°C

^{*}Specified board: 58.0×54.0×1.6mm (glass epoxy board)

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LV5026M

Recommended Operating Conditions at Ta = 25°C

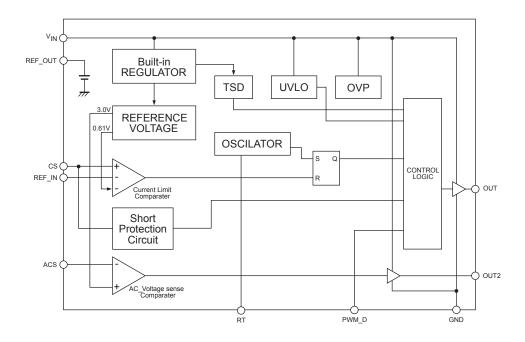
Parameter	Symbol	Conditions	Ratings	Unit
Input voltage	V _{IN}		8.5 to 42	V

Electrical Characteristics at Ta = 25 °C, $V_{\mbox{IN}} = 12 \mbox{V}$, unless otherwise specified.

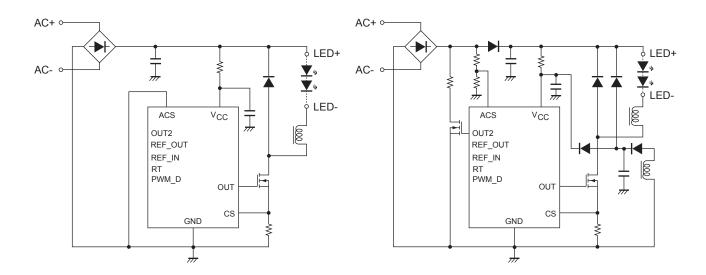
Davanatas	O. mahal	O selection	Ratings			l leit
Parameter	Symbol	Conditions	min	typ	max	Unit
Reference Voltage block						
Built-in Reference Voltage	VREF		0.585	0.605	0.625	>
VREF V _{IN} regulation	VREF_LN	V _{IN} = 8.5 to 24V		±0.5		%
Reference Output Voltage	REFOUT	I _{REFOUT} = 0.5mA		3.0		V
- Maximum load	REFOUT_MAX		0.5			mA
- equivalent output impedance	REFOUT_RO			10		Ω
Under Voltage Lockout						
Operation Start Input Voltage	UVLOON		8	9	10	V
Operation Stop Input Voltage	UVLOOFF		6.3	7.3	8.3	V
Hysterisys Voltage	UVLOH			1.7		V
Oscillation					•	
Frequency	FOSC1	RT = OPEN	40	50	60	kHz
	FOSC2	RT=REF_OUT	55	70	85	kHz
FOSC1 Switch voltage	Vosc1		2		5	V
FOSC2 Switch voltage	V _{OSC} ²				0.5	V
Maximum Duty	MAXDuty			93		%
Comparator	1					
Input offset Voltage	V _{IO} _VR			1	10	mV
(Between CS and VREF)						
Input offset Voltage	V _{IO} _RI			1	10	mV
(Between CS and REFOUT)						
Input current	IIOCS			160		nA
	IIOREF			80		nA
CS pin max voltage	VOM				1	V
malfunction prevention mask time	TMSK			150		ns
PWM_D Circuit			1			
OFF voltage	V _{OFF}		2		5	V
ON voltage	V _{ON}		0		0.6	V
Thermal protection Circuit	- 014					
Thermal shutdown temperature	TSD	*Design guarantee		165		°C
Thermal shutdown hysterisys	ΔTSD	*Design guarantee		30		°C
Drive Circuit	4105	Doorgii guarantoo		00		
OUT sink current	IOI		500	1000		mA
OUT source current	100			120		mA
Minimum On time	TMIN			200	300	ns
TRIAC Stabilization Circuit	1	<u> </u>		200	000	
Threshold of OUT2	VACS	OUT2=High [less than right record]	2.8	3.0	3.2	V
OUT2 sink current	I _O 2I	VIN=12V, OUT2=6V	2.0	0.6	0.2	mA
OUT2 source current	I _O 20	VIN=12V, OUT2=6V		0.6		mA
V _{CC} current	1 .0=0	12., 33.2 37	1	5.0		7101
UVLO mode V _{IN} current	I _{CC} OFF	V _{IN} <uvloon< td=""><td></td><td>80</td><td>120</td><td>μА</td></uvloon<>		80	120	μА
Normal mode V _{IN} current	ICCON	V _{IN} >UVLOON, OUT = OPEN		0.6	120	mΑ
V _{IN} Over Voltage Protection Cir	•	- IIIN	1	0.0		
V _{IN} over voltage protection	V _{IN} OVP		24	27	30	V
voltage	VIINOVI		24	21	30	v
VIN Current at OVP	IINOVP	V _{IN} =30V	0.7	1.0	1.5	mA
CS terminal abnormal sensing	circuit		1	L		
Abnormal sensing voltage	CSOCP			1.9		V
	to de la companya	not tested before shipment)	1	l l		

^{*:} Design guarantee (value guaranteed by design and not tested before shipment)

Block Diagram

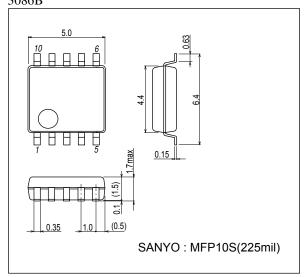


Sample Application Circuit

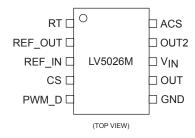


Package Dimensions

unit : mm (typ) 3086B



Pin Assignment

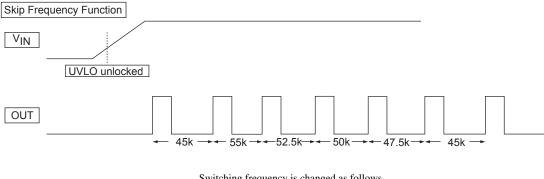


Pin Function

in Fur		
Pin No.	Pin name	Function
1	RT	Switching Frequency selection Pin.
		[L or Open: 50kHz Switching / H(2V – 5V): 70 kHz Switching]
2	REF_OUT	Built-in 3V Regulate out Pin.
		[If this function isn't used, please connect GND or no connection.]
3	REF_IN	External LED current Limit Setting Pin.
		If less than VREF (0.605V) voltage is input, Peak current value is used at the input voltage. If more than Vref voltage is
		input, it is done at VREF voltage.
		[If this function isn't used, please connect nothing.]
4	CS	LED current sensing pin.
		When this pin voltage exceeds VREF (or REF_IN), external FET is OFF. And if the voltage of the pin exceeds 1.9V,
		LV5026M turns to latch-off mode.
5	PWM_D	PWM DIMMING pin.
		[L or open :normal operation, H: Stop operation]
6	GND	GND pin
7	OUT	Driving the external FET Gate pin.
8	V _{IN}	Power supply pin.
		Operation: V _{IN} > UVLOON
		Stop: V _{IN} < UVLOOFF
		Switching Stop: V _{IN} > V _{IN} OVP
9	OUT2	This terminal is driving the FET which is stabilized the TRIAC application. If ACS is less than 3V, OUT2 outputs VIN.
		[If this function isn't used, please connect nothing.]
10	ACS	This terminal is sensing the AC Voltage.
		[If this function isn't used, please connect GND.]

Skip frequency function

LV5026M contains the skip frequency function for reduction of the peak value of conduction noise. This function changes the frequency as follows.



Switching frequency is changed as follows. ... $\times 0.9 \rightarrow \times 1.1 \rightarrow \times 1.05 \rightarrow \times 1 \rightarrow \times 0.95 \rightarrow \times 0.9 \rightarrow \times 1.1$... It's repeated by this loop.

CS pin abnormal stop function

If the voltage of the pin exceeds 1.9V, LV5026M turns to latch-off mode and switching is stopping.

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